## 2N6298 2N6299 PNP 2N6300 2N6301 NPN

# COMPLEMENTARY SILICON DARLINGTON POWER TRANSISTORS



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## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N6298 series devices are complementary silicon Darlington power transistors manufactured by the epitaxial base process designed for high gain amplifier and medium speed switching applications.

**MARKING: FULL PART NUMBER** 



		2N6298	2N6299	
MAXIMUM RATINGS: (T <sub>C</sub> =25°C)	SYMBOL	2N6300	<u>2N6301</u>	UNITS
Collector-Base Voltage	$V_{CBO}$	60	80	V
Collector-Emitter Voltage	VCEO	60	80	V
Emitter-Base Voltage	$V_{EBO}$	5.0		V
Continuous Collector Current	IC	8	.0	Α
Peak Collector Current	ICM	1	6	Α
Continuous Base Current	ΙΒ	12	20	mA
Power Dissipation	$P_{D}$	7	5	W
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to	+200	°C
Thermal Resistance	$\Theta$ JC	2.5	33	°C/W

ELECTRICAL CHARACTERISTICS: (T <sub>C</sub> =25°C unless otherwise noted)							
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS			
ICEV	V <sub>CE</sub> =Rated V <sub>CEO</sub> , V <sub>BE</sub> =1.5V		0.5	mA			
ICEV	V <sub>CE</sub> =Rated V <sub>CEO</sub> , V <sub>BE</sub> =1.5V, T <sub>C</sub> =150°C		5.0	mA			
ICEO	V <sub>CE</sub> =½Rated V <sub>CEO</sub>		0.5	mA			
I <sub>EBO</sub>	V <sub>EB</sub> =5.0V		2.0	mA			
BVCEO	I <sub>C</sub> =100mA (2N6298, 2N6300)	60		V			
BVCEO	I <sub>C</sub> =100mA (2N6299, 2N6301)	80		V			
V <sub>CE</sub> (SAT)	I <sub>C</sub> =4.0A, I <sub>B</sub> =16mA		2.0	V			
VCE(SAT)	I <sub>C</sub> =8.0A, I <sub>B</sub> =80mA		3.0	V			
V <sub>BE(SAT)</sub>	I <sub>C</sub> =8.0A, I <sub>B</sub> =80mA		4.0	V			
V <sub>BE(ON)</sub>	$V_{CE}=3.0V, I_{C}=4.0A$		2.8	V			
hFE	$V_{CE}=3.0V, I_{C}=4.0A$	750	18K				
h <sub>FE</sub>	$V_{CE}$ =3.0V, $I_{C}$ =8.0A	100					
h <sub>fe</sub>	$V_{CE}$ =3.0V, $I_{C}$ =3.0A, f=1.0kHz	300					
f <sub>T</sub>	$V_{CE}$ =3.0V, $I_{C}$ =3.0A, f=1.0MHz	4.0		MHz			
C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=100kHz (NPN types)		200	pF			
$C_{ob}$	$V_{CB}$ =10V, $I_E$ =0, f=100kHz (PNP types)		300	pF			

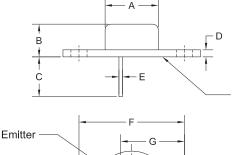
R3 (2-September 2014)

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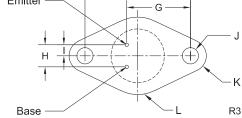
# COMPLEMENTARY SILICON DARLINGTON POWER TRANSISTORS



## **TO-66 CASE - MECHANICAL OUTLINE**



Seating Plane:
The seating plane must be within 0.001" concave to 0.004" convex within 0.600" diameter from the center of the device.



MARKING: FULL PART NUMBER

DIMENSIONS								
	INC	HES	MILLIMETERS					
SYMBOL	MIN	MAX	MIN	MAX				
A (DIA)	0.470	0.500	11.94	12.70				
В	0.250	0.340	6.35	8.64				
С	0.360	-	9.14	-				
D	0.050	0.075	1.27	1.91				
E (DIA)	0.028	0.034	0.71	0.86				
F	0.956	0.964	24.28	24.48				
G	0.570	0.590	14.48	14.99				
Н	0.190	0.210	4.83	5.33				
I	0.093	0.107	2.36	2.72				
J (DIA)	0.142	0.152	3.61	3.86				
K (RAD)	0.141		3.	58				
L (RAD)	0.345		8.76					
TO 66 (DE)/(D2)								

TO-66 (REV:R3)

R3 (2-September 2014)

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### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

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